SURFACE MOUNT CHIP LED LAMP SPECIFICATION

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1.1

● COMMODITY: SURFACE MOUNT CHIP LED LAMP

●DEVICE NUMBER: BL-HE1Y034B

●ELECTRICAL AND OPTICAL CHARACTERISTICS (Ta=25°C)

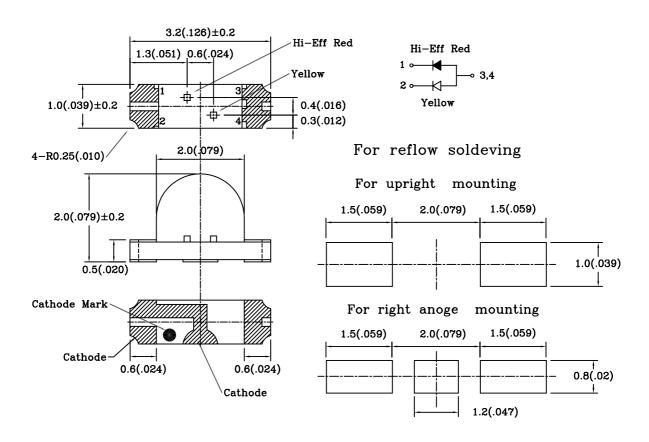
Chip Peak Dominant		Lens	Absolute Maximum Rating			Electro-optical Data (At 20mA)			Viewing Angle			
Emitted Color	Wave Length λ p(nm)	Wave Length λ d(nm)	Appearance			Peak If(mA)	Vf(V) Iv Ty (mcc		cd)	$\begin{array}{c} 2\theta 1/2 \\ \text{(deg)} \end{array}$		
	λ p(mn)	λ u(iiii)		(11111)	(111))	(1111 1)	II(IIII I)	Тур.	Max.	Min	Typ.	
Hi-Eff Red	640	628±5	Water Clear	35	80	30	100	2.0	2.6	3.7	10.0	100
Yellow	587	585		35	100	30	100	2.1	2.6	2.4	7.0	100

Remark: Viewing angle is the Off-axis angle at which the luminous intensity is half the axial luminous intensity.

● ABSOLUTE MAXIMUM RATINGS (Ta=25°C)

Reverse Voltage			5V
Reverse Current (V _R =5V)			
Operating Temperature Range	25°C	\sim	80°C
Storage Temperature Range	30℃	\sim	85℃

●PACKAGE DIMENSIONS



NOTES: 1.All dimensions are in millimeters (inches).

- 2. Tolerance is \pm 0.10mm (0.004) unless otherwise specified.
- 3. Specifications are subject to change without notice.
- 4. Condition for IFp is pulse of 1/10 duty and 0.1 msec width.

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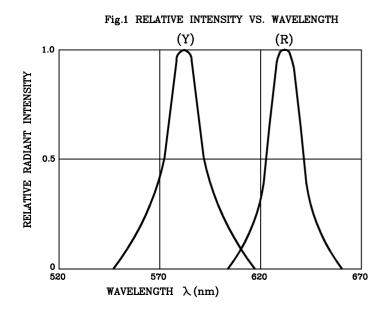


Fig.2 FORWARD CURRENT DERATING CURVE

60

WH
50

10

20

40

60

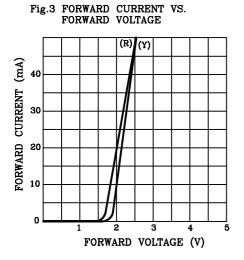
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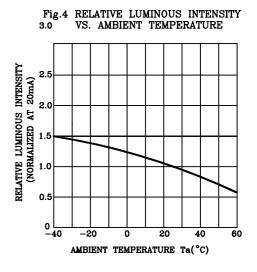
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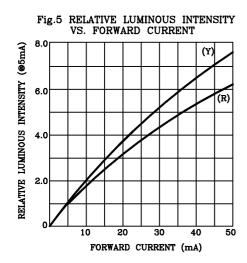
AMBIENT TEMPERATURE Ta(°C)

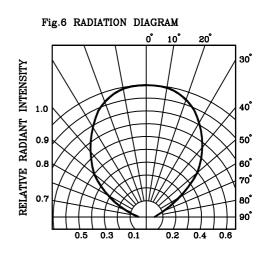
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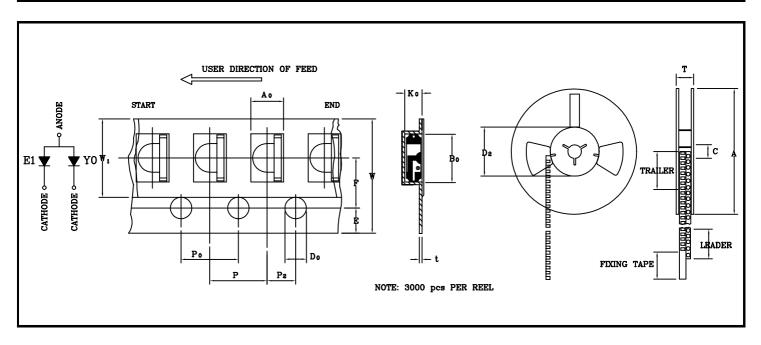
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● COMMODITY: SURFACE MOUNT CHIP LED LAMP

DEVICE NUMBER: BL-HE1Y034B-TR PAGE:

●ELECTRICAL AND OPTICAL CHARACTERISTICS (Ta=25°C)

		SPECIFICATION					
ITEM	SYMBOL	Mini	mum	Maximum			
		mm	inch	mm	inch		
Tape Feed Hole Diameter (DIA)	D_0	1.40	0.055	1.60	0.063		
Feed Hole Location	Е	1.65	0.064	1.85	0.073		
Centers Line Dimensions Length Direction	F	3.45	0.135	3.55	0.139		
Compartment Depth	K_0	1.55	0.061	1.65	0.064		
Compartment Pitch	P	3.90	0.153	4.10	0.161		
Sprocket Hole Diameter	P_0	3.90	0.153	4.10	0.161		
Centers Line Dimensions Length Direction	P_2	1.95	0.076	2.05	0.080		
Carrier Tape Thickness	t	_	_	0.30	0.012		
Carrier Tape Width	W	7.70	0.303	8.30	0.326		
Flange Diameter	A	178.0	7.008	180.0	7.087		
Hub Spindle Hole	С	12.50	0.492	13.50	0.531		
Hub Diameter	D_2	70.00	2.755	72.00	2.830		
Fixing Tape Width	W_1	5.25	0.206	5.35	0.210		
Flange Space Between Flanges	T	16.00	0.629	18.40	0.724		
Compartment Length	A_0	2.35	0.093	2.45	0.096		
Compartment Width	B_0	3.35	0.132	3.45	0.136		



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RELIABILITY TEST

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Classification	Test Item	Reference Standard	Test Conditions	Result
	Operation Life	MIL-STD-750:1026 MIL-STD-883:1005 JIS C 7021 :B-1	Connect with a power If=20mA Ta=Under room temperature Test time=1,000hrs	0/20
Endurance	High Temperature High Humidity Storage	MIL-STD-202:103В JIS C 7021 :В-11	Ta=+65°C±5°C RH=90%-95% Test time=1,000hrs	0/20
Test	High Temperature Storage	MIL-STD-883:1008 JIS C 7021 :В-10	High Ta=+85°C±5°C Test time=1,000hrs	0/20
	Low Temperature Storage	JIS-C-7021 :B-12	Low Ta=-35°C±5°C Test time=1,000hrs	0/20
	Cycling	MIL-STD-202:107D MIL-STD-750:1051 MIL-STD-883:1010 JIS C 7021 :A-4	-35° C $\sim +25^{\circ}$ C $\sim +85^{\circ}$ C $\sim +25^{\circ}$ C 60min 20min 60min 20min Test Time=5cycle	0/20
Environmental Test	Thermal Shock	MIL-STD-202:107D MIL-STD-750:1051 MIL-STD-883:1011	$+85^{\circ}\text{C}\pm5^{\circ}\text{C} \sim -35^{\circ}\text{C}\pm5^{\circ}\text{C}$ 20min 20min Test Time=10cycle	0/20
	IK esistance	MIL-STD-202:201A MIL-STD-750:2031 JIS C 7021 :A-1	Preheating: 140°C-160°C, within 2 minutes. Operation heating: 235°C (Max.), within 10seconds. (Max.)	0/20

JUDGMENT CRITERIA OF FAILURE FOR THE RELIABILITY

Measuring items	Symbol	Measuring conditions	Judgement criteria for failure
Forward voltage	$V_{F}(V)$	If=20mA	Over Ux1.2
Reverse current	Ir(uA)	Vr=5V	Over Ux2
Luminous intensity	Iv (mcd)	If=20mA	Below SX0.5

Note: 1.U means the upper limit of specified characteristics. S means initial value.

2.Measurment shall be taken between 2 hours and after the test pieces have been returned to normal ambient conditions after completion of each test.

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1. **SOLDERING:**

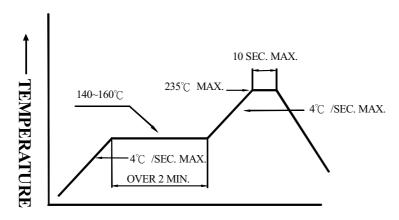
Manual Of Soldering The temperature of the iron tip should not be higher than 300° C (572°F) and Soldering within 3 seconds per solder-land is to be observed.

Reflow Soldering

Preheating: 140° C $\sim 160^{\circ}$ C $\pm 5^{\circ}$ C, within 2 minutes.

Operation heating: 235°C (MAX.) within 10 seconds.(Max)

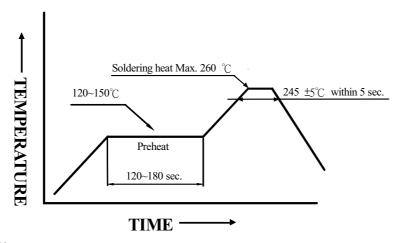
Gradual Cooling (Avoid quenching).



TIME -**DIP soldering (Wave Soldering)**

Preheating: 120°C~150°C, within 120~180 sec. Operation heating: 245°C±5°C within 5 sec.260°C (Max)

Gradual Cooling (Avoid quenching).



2. **Handling:**

Care must be taken not to cause to the epoxy resin portion of BRIGHT LEDs while it is exposed to high temperature. Care must be taken not rub the epoxy resin portion of BRIGHT LEDs with hard or sharp article such as the sand blast and the metal hook

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3. Notes for designing:

Care must be taken to provide the current limiting resistor in the circuit so as to drive the BRIGHT LEDs within the rated figures. Also, caution should be taken not to overload BRIGHT LEDs with instantaneous voltage at the turning ON and OFF of the circuit.

When using the pulse drive care must betaken to keep the average

Current within the rated figures. Also, the circuit should be designed soas be subjected to reverse voltage when turning off the BRIGHT LEDs.

4. Storage:

BRIGHT LEDs as soon as possible after unpacking the sealed envelope If the envelope is still pack, to store it in the environment as following:

- (1) Temperature: 5° C- 30° C(41° F)Humidity: RH 60% Max.
- (2) After this bag is opened, devices that will be applied to infrared reflow, vapor-phase reflow, or equivalent soldering process must be:
- a. Completed within 24 hours.
- b. Stored at less than 30% RH.
- (3) Devices require baking before mounting, if:
 - (2) a or (2) b is not met.
- (4) If baking is required, devices must be baked under below conditions: 12 hours at $60^{\circ}\text{C} \pm 3^{\circ}\text{C}$.

5. Package and Marking of Products:

In order to avoid the absorption of moisture .It is recommended to solder

- (1) Package: Products are packed in one bag of 3000 pcs (one taping reel) and a label is attached on each bag.
- (2) Marking:

